

ECEHCAB5VB

Low-Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

The ECEHCAB5VB is designed with ECORE Punch-Through process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

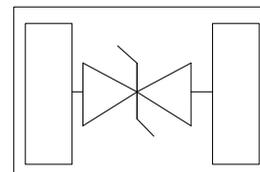
This series has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

Features

- Peak Power Dissipation –360 W (8 x 20 us Waveform)
- Stand-off Voltage: 5.0 V
- Low capacitance for high-speed interfaces
- Replacement for MLV (0402)
- Protects I/O、 VCC Port
- Low Clamping Voltage
- Low Leakage Current: 0.2uA
- Low Capacitance
- Response Time is < 1 ns
- Meets MSL 1 Requirements
- ROHS compliant



DFN1006



Main applications

- Serial and Parallel Ports
- Notebooks, Desktops, Servers
- Projection TV
- Cellular handsets and accessories
- Portable instrumentation
- Peripherals

Protection solution to meet

- IEC61000-4-2 (ESD) ±30kV (air), ±30kV (contact)
- IEC61000-4-5 (Lightning) 30A (8/20us)

Ordering Information

Device	Qty per Reel	Reel Size
ECEHCAB5VB	10000pcs	7inch

Maximum ratings (Tamb=25°C Unless Otherwise Specified)			
Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20µs waveform)	P _{PPP}	360	Watts
Peak pulse current (tp=8/20µs waveform)	I _{PP}	30	A
ESD Rating per IEC61000-4-2:	Contact	30	KV
	Air	30	
Lead Soldering Temperature	T _L	260 (10 sec.)	°C
Operating Temperature Range	T _J	-55 ~ 125	°C
Storage Temperature Range	T _{STG}	-55 ~ 150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

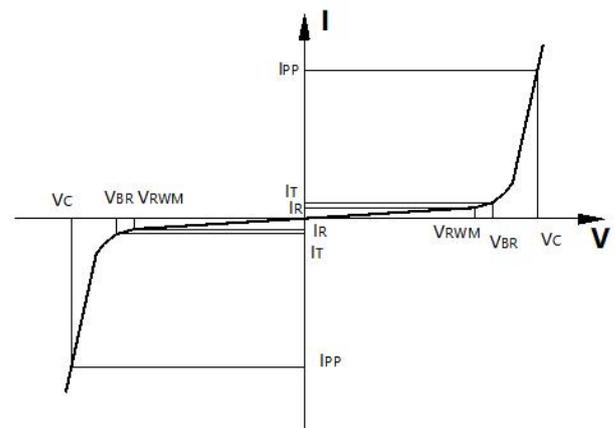
*Other voltages may be available upon request.

1. Non-repetitive current pulse, per Figure 1.

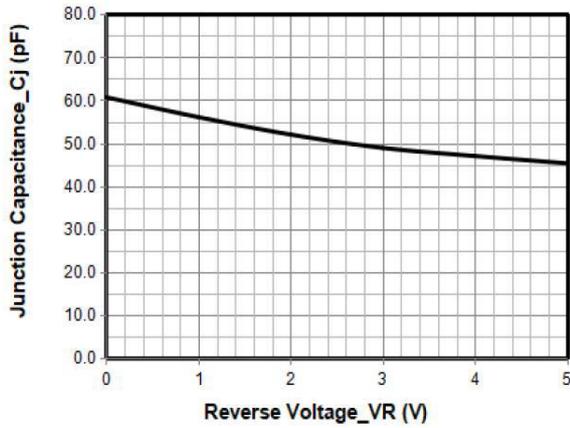
Electrical characteristics (Tamb=25°C Unless Otherwise Specified)						
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{RWM}	Reverse Working Voltage				5	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA,	6	7	9	V
I _R	Reverse Leakage Current	V _{RWM} = 5V,			0.2	µA
V _C	Clamping Voltage	I _{PP} = 1A, tp =8/20µs,			7	V
		I _{PP} = 30A, tp =8/20µs,			13	V
C _J	Junction Capacitance	V _R = 0V, f = 1MHz,		60		pF

Junction capacitance is measured in V_R=0V,F=1MHz

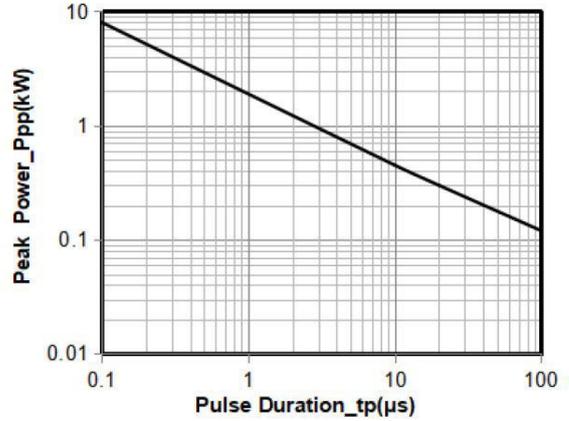
Symbol	Parameter
V _{RWM}	Working Peak Reverse Voltage
V _{BR}	Breakdown Voltage @ I _T
V _C	Clamping Voltage @ I _{PP}
I _T	Test Current
I _{RM}	Leakage current at V _{RWM}
I _{PP}	Peak pulse current
C _O	Off-state Capacitance
C _J	Junction Capacitance



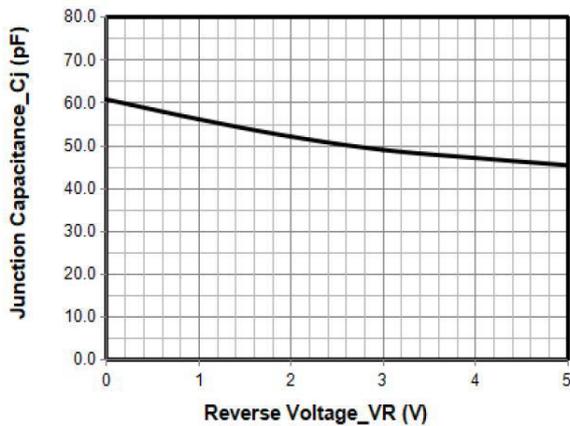
Typical electrical characterist applications



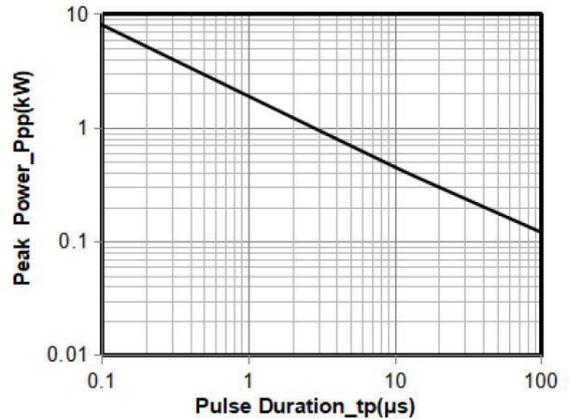
Junction Capacitance vs. Reverse Voltage



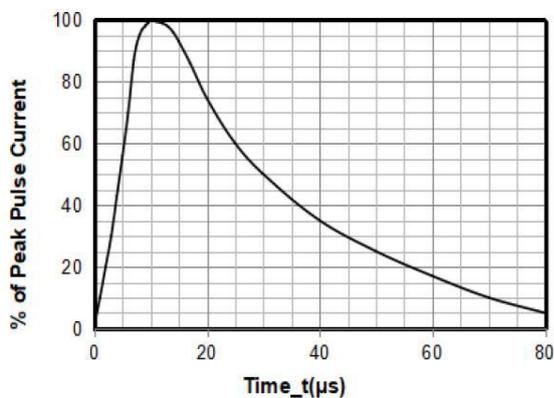
Peak Pulse Power vs. Pulse Time



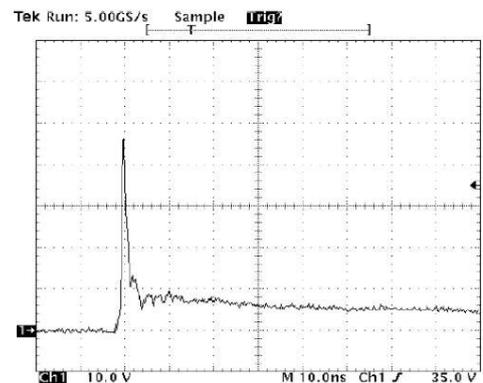
Junction Capacitance vs. Reverse Voltage



Peak Pulse Power vs. Pulse Time



8 X 20μs Pulse Waveform



Note: Data is taken with a 10x attenuator
ESD Clamping Voltage
8 kV Contact per IEC61000-4-2

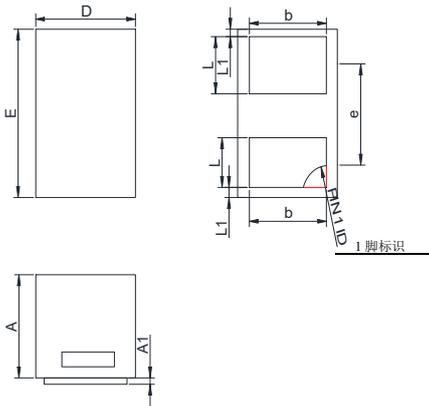
Package Information

DFN1006

Mechanical Data

Case:DFN1006

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters	
	Min	Max
A	0.40	0.50
A1	0.00	0.05
D	0.55	0.65
E	0.95	1.05
b	0.45	0.55
e	0.65TYP	
L	0.2	0.32
L1	0.05REF	